

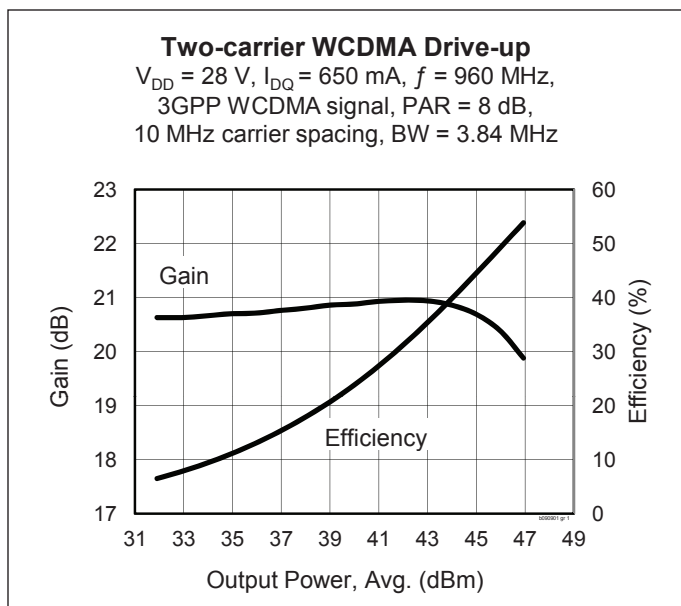
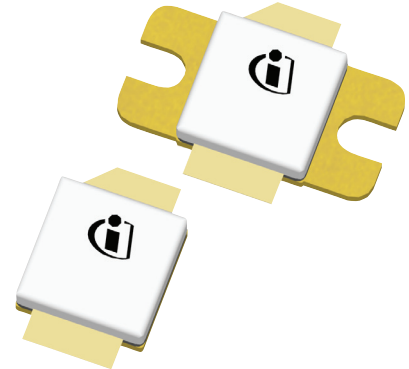
## Thermally-Enhanced High Power RF LDMOS FETs 90 W, 28 V, 920 – 960 MHz

### Description

The PTFB090901EA and PTFB090901FA are 90-watt LDMOS FETs intended for use in multi-standard cellular power amplifier applications in the 920 to 960 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced packages. Manufactured with Infineon's advanced LDMOS process, these devices provide excellent thermal performance and superior reliability.

PTFB090901EA  
Package H-36265-2

PTFB090901FA  
Package H-37265-2



### Features

- Input and output internal matching
- Typical CW performance, 960 MHz, 28 V
  - Output power at  $P_{1dB} = 90\text{ W}$
  - Efficiency = 65%
- Typical two-carrier WCDMA performance, 960 MHz, 28 V
  - Average output power = 20 W
  - Linear Gain = 20.8 dB
  - Efficiency = 35%
  - Intermodulation distortion = -35 dBc
- Integrated ESD protection
- Low thermal resistance
- Pb-free and RoHS-compliant
- Capable of handling 10:1 VSWR @ 28 V, 90 W (CW) output power

### RF Characteristics

#### Single-carrier WCDMA Specifications (tested in Infineon test fixture)

$V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 650\text{ mA}$ ,  $P_{OUT} = 25\text{ W}$  average,  $f = 960\text{ MHz}$   
 3GPP signal, PAR = 10 dB @ 0.01% CCDF probability, channel bandwidth = 3.84 MHz

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	$G_{ps}$	19	19.5	—	dB
Drain Efficiency	$\eta_D$	36	40	—	%
Adjacent Channel Power Ratio	ACPR	—	-35	-31.5	dBc

All published data at  $T_{CASE} = 25^\circ\text{C}$  unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

## RF Characteristics (cont.)

**Two-tone Specifications** (not subject to production test—verified by design/characterization in Infineon test fixture)  
 $V_{DD} = 28\text{ V}$ ,  $I_{DQ} = 650\text{ mA}$ ,  $P_{OUT} = 70\text{ W PEP}$ ,  $f = 960\text{ MHz}$ , tone spacing = 1 MHz

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	$G_{ps}$	—	19.5	—	dB
Drain Efficiency	$\eta_D$	—	48	—	%
Intermodulation Distortion	IMD	—	-30	—	dBc

## DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-source Breakdown Voltage	$V_{GS} = 0\text{ V}$ , $I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	1.0	$\mu\text{A}$
	$V_{DS} = 63\text{ V}$ , $V_{GS} = 0\text{ V}$	$I_{DSS}$	—	—	10.0	$\mu\text{A}$
On-state Resistance	$V_{GS} = 10\text{ V}$ , $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.123	—	$\Omega$
Operating Gate Voltage	$V_{DS} = 28\text{ V}$ , $I_{DQ} = 650\text{ mA}$	$V_{GS}$	—	3.8	—	V
Gate Leakage Current	$V_{GS} = 10\text{ V}$ , $V_{DS} = 0\text{ V}$	$I_{GSS}$	—	—	1.0	$\mu\text{A}$

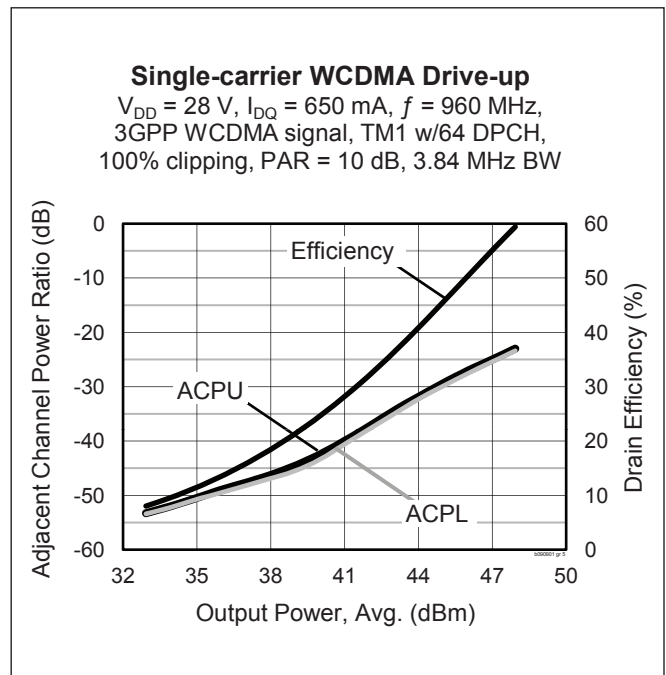
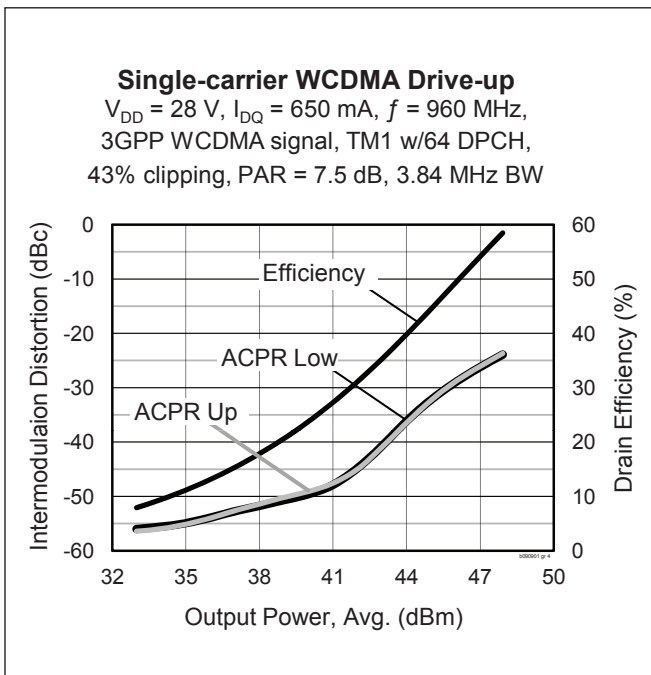
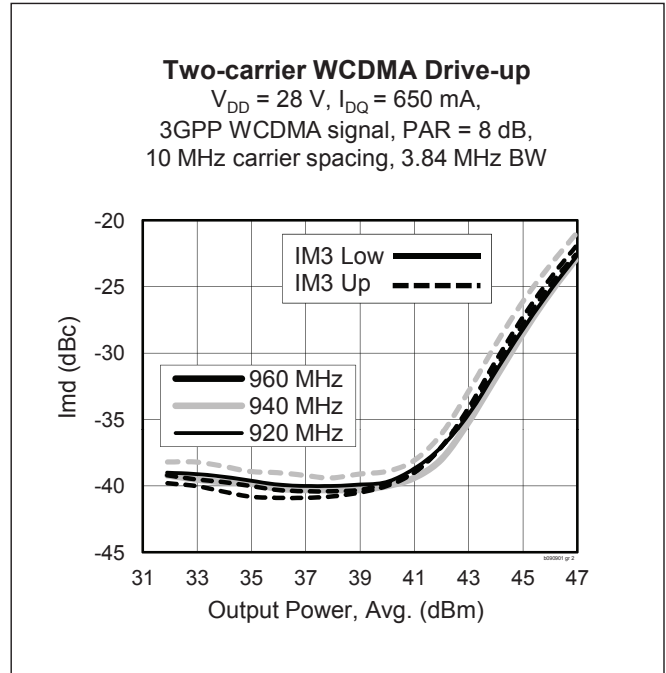
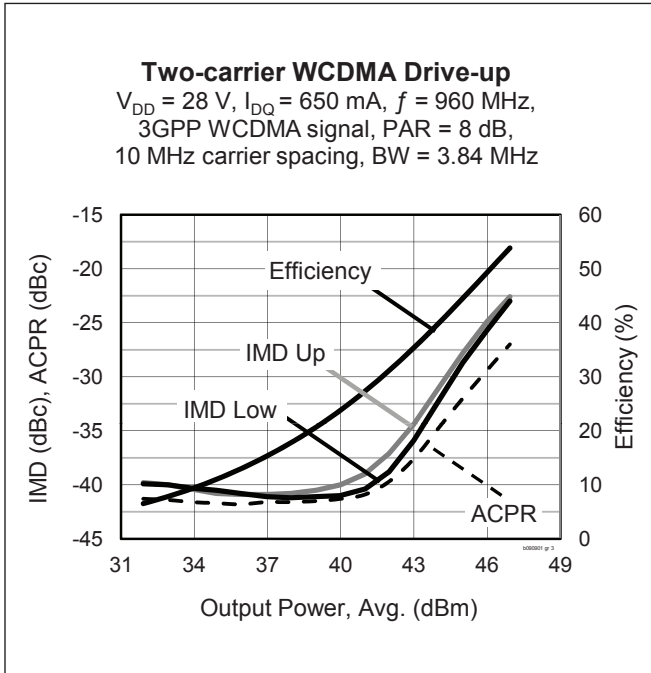
## Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-source Voltage	$V_{DSS}$	65	V
Gate-source Voltage	$V_{GS}$	-6 to +10	V
Junction Temperature	$T_J$	200	$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-40 to +150	$^{\circ}\text{C}$
Thermal Resistance ( $T_{CASE} = 70^{\circ}\text{C}$ , 85 W CW)	$R_{\theta JC}$	0.73	$^{\circ}\text{C/W}$

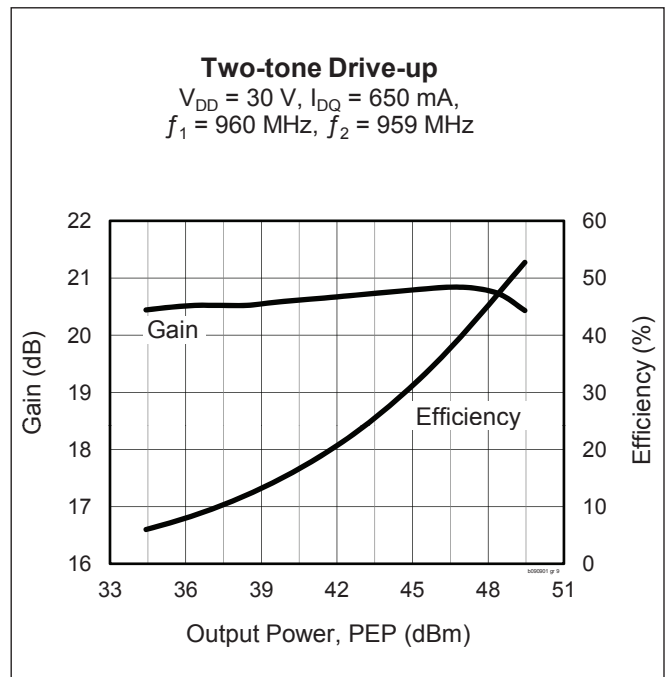
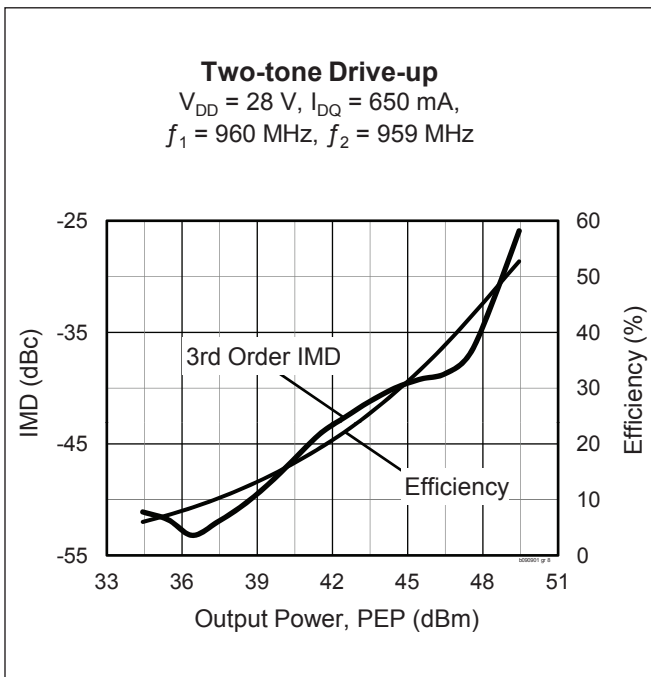
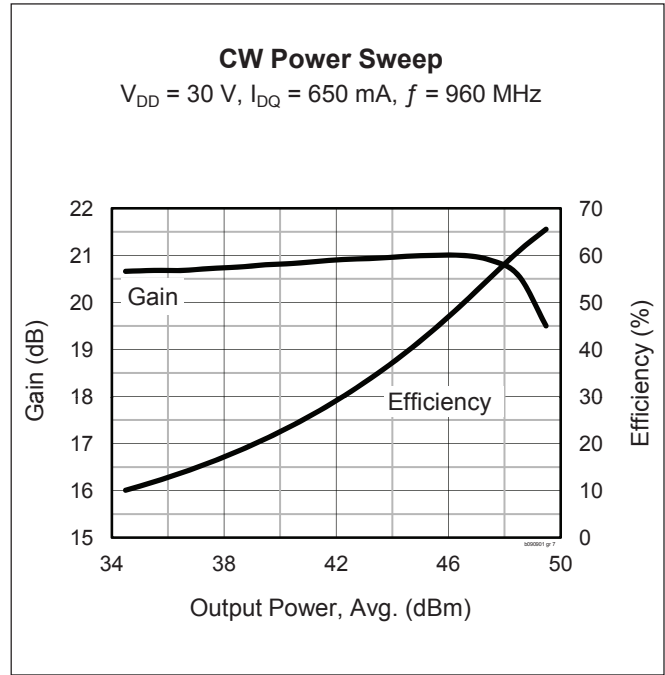
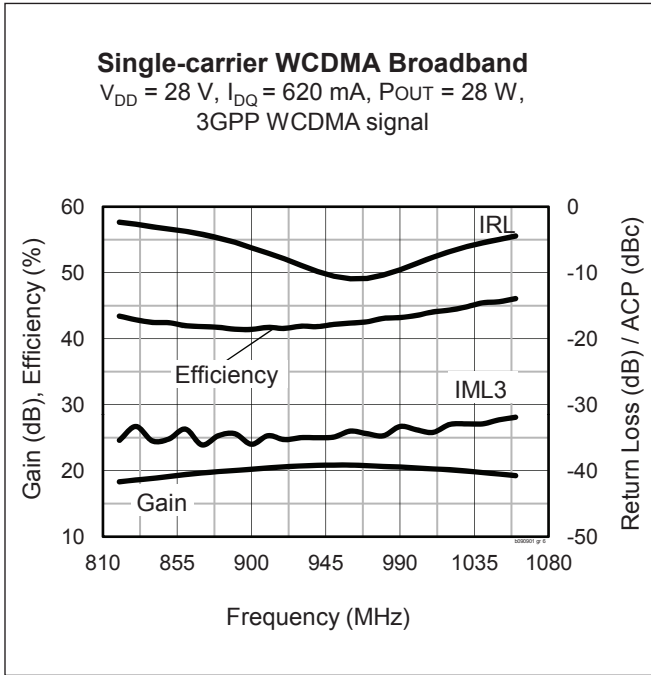
## Ordering Information

Type and Version	Order Code	Package	Package Description	Shipping
PTFB090901EA V2 R0	PTFB090901EAV2R0XTMA1	H-36265-2	Ceramic open-cavity, bolt-down	Tape & Reel, 50 pcs
PTFB090901EA V2 R250	PTFB090901EAV2R250XTMA1	H-36265-2	Ceramic open-cavity, bolt-down	Tape & Reel, 250 pcs
PTFB090901FA V2 R0	PTFB090901FAV2R0XTMA1	H-37265-2	Ceramic open-cavity, earless	Tape & Reel, 50 pcs
PTFB090901FA V2 R250	PTFB090901FAV2R250XTMA1	H-37265-2	Ceramic open-cavity, earless	Tape & Reel, 250 pcs

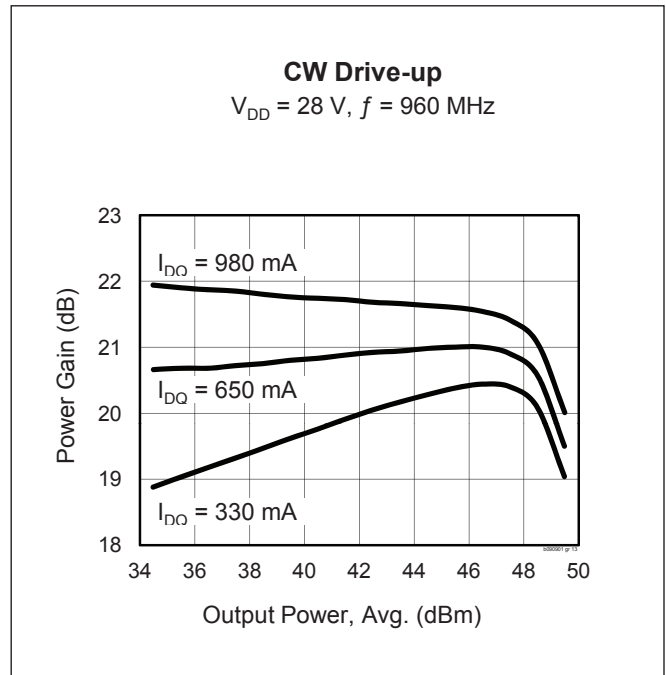
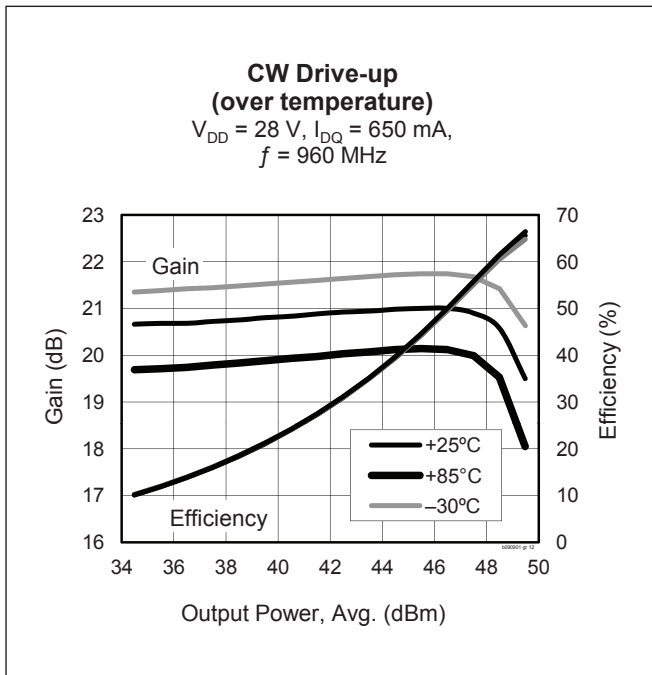
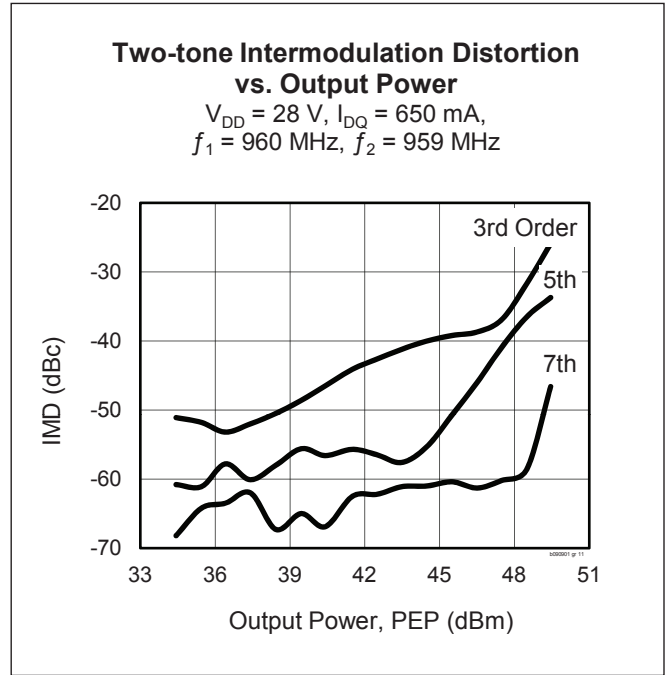
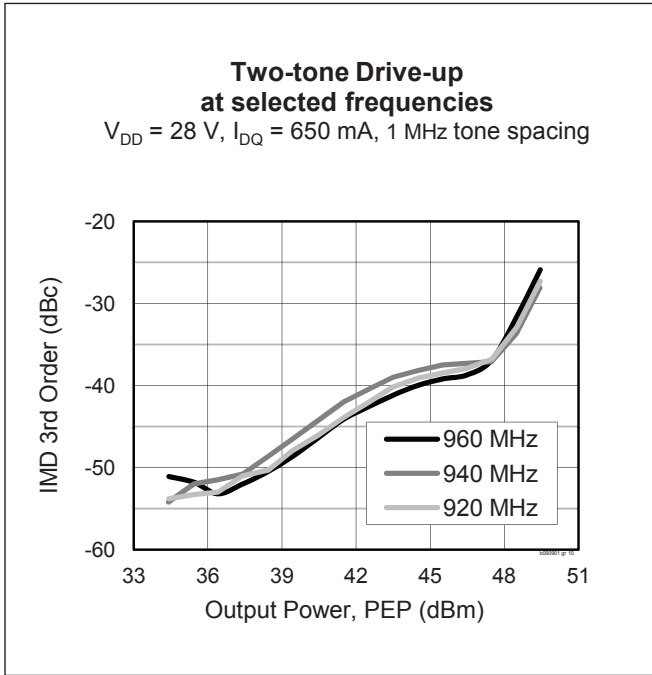
**Typical Performance** (data taken in a production test fixture)



Typical Performance (cont.)

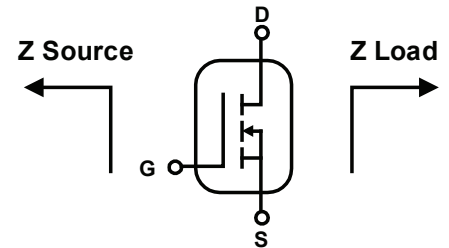


Typical Performance (cont.)



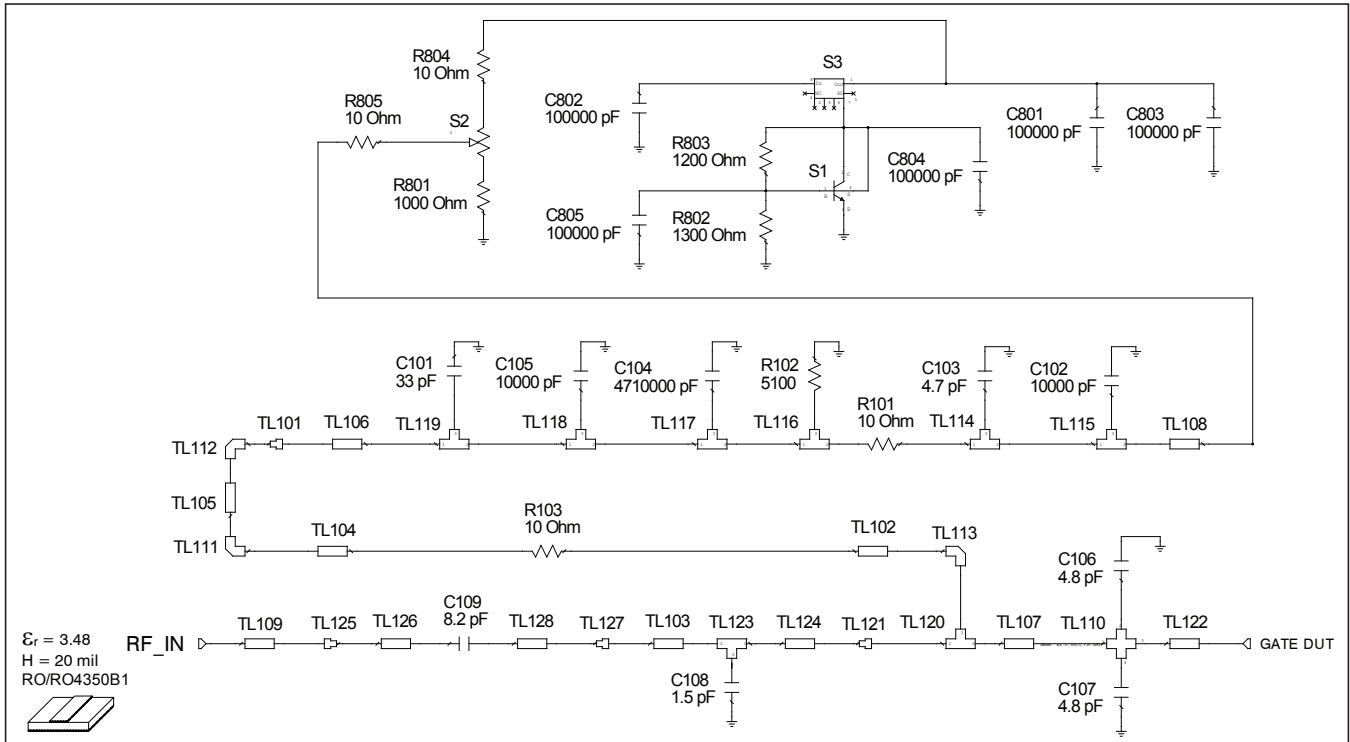
### Broadband Circuit Impedance

Frequency MHz	Z Source $\Omega$		Z Load $\Omega$	
	R	jX	R	jX
900	2.3	-6.4	3.8	-2.6
920	2.2	-6.2	3.6	-2.3
940	2.1	-6.0	3.5	-2.1
960	1.9	-5.8	3.4	-1.8
980	1.8	-5.6	3.3	-1.6

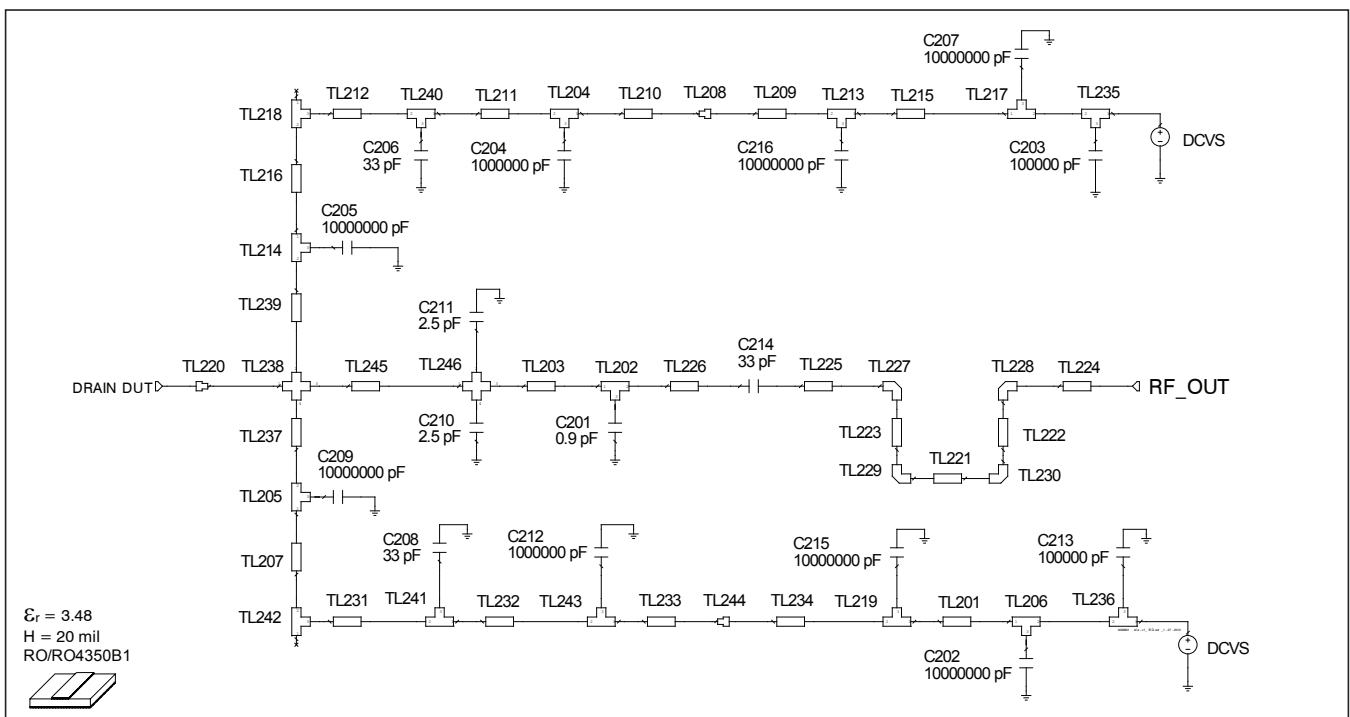


See next page for reference circuit information

Reference Circuit



Reference circuit input schematic for  $f = 960$  MHz



Reference circuit output schematic for  $f = 960$  MHz

## Reference Circuit (cont.)

### Reference Circuit Assembly

DUT	PTFB090901EA or PTFB090901FA		
Reference Circuit Part No.	LTN/PTFB090901EA (PTFB090901EA)	LTN/PTFB090901FA (PTFB090901FA)	
PCB	Rogers RO4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.48$		
Find Gerber files for this test fixture on the Infineon Web site at <a href="http://www.infineon.com/rfpower">http://www.infineon.com/rfpower</a>			

### Electrical Characteristics at 960 MHz

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
<b>Input</b>			
TL102	0.0064 $\lambda$ , 69.6 $\Omega$	W = 0.65, L = 1.23	W = 25, L = 48
TL103	0.1238 $\lambda$ , 51.53 $\Omega$	W = 1.1, L = 23.38	W = 43, L = 921
TL104	0.1658 $\lambda$ , 69.6 $\Omega$	W = 0.65, L = 31.91	W = 25, L = 1256
TL105	0.0205 $\lambda$ , 69.6 $\Omega$	W = 0.65, L = 3.94	W = 25, L = 155
TL106	0.0014 $\lambda$ , 26.81 $\Omega$	W = 2.79, L = 0.25	W = 110, L = 10
TL107	0.0195 $\lambda$ , 7.47 $\Omega$	W = 12.37, L = 3.37	W = 487, L = 133
TL108	0.0014 $\lambda$ , 26.81 $\Omega$	W = 2.79, L = 0.25	W = 110, L = 10
TL109	0.0369 $\lambda$ , 51.53 $\Omega$	W = 1.1, L = 6.97	W = 43, L = 275
TL114, TL115, TL116, TL117, TL118, TL119	0.014 $\lambda$ , 26.81 $\Omega$	W1 = 2.79, W2 = 2.79, W3 = 2.54	W1 = 110, W2 = 110, W3 = 100
TL120	0.0037 $\lambda$ , 7.47 $\Omega$	W1 = 12.37, W2 = 12.37, W3 = 0.65	W1 = 487, W2 = 487, W3 = 25
TL122	0.0294 $\lambda$ , 7.47 $\Omega$	W = 12.37, L = 5.08	W = 487, L = 200
TL123	0.0094 $\lambda$ , 51.53 $\Omega$	W1 = 1.1, W2 = 1.1, W3 = 1.78	W1 = 43, W2 = 43, W3 = 70
TL124	0.0183 $\lambda$ , 51.53 $\Omega$	W = 1.1, L = 3.45	W = 43, L = 136
TL126, TL128	0.0055 $\lambda$ , 34.08 $\Omega$	W = 2.03, L = 1.02	W = 80, L = 40

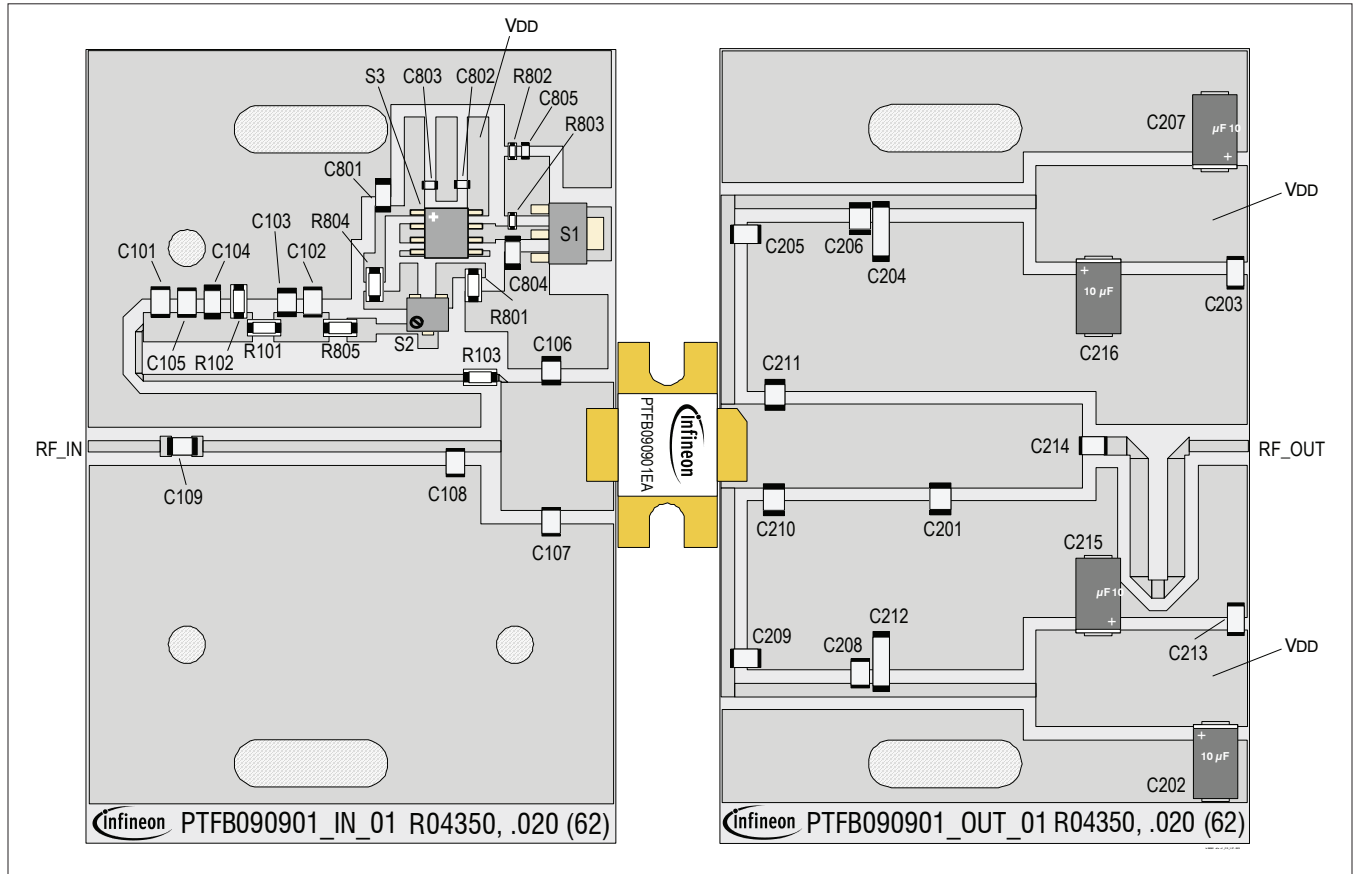


## Reference Circuit (cont.)

### Electrical Characteristics at 960 MHz (cont.)

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
<b>Output</b>			
TL201	0.055 $\lambda$ , 9.74 $\Omega$	W = 9.25, L = 9.65	W = 364, L = 380
TL202	0.010 $\lambda$ , 11.08 $\Omega$	W1 = 8, W2 = 8, W3 = 1.78	W1 = 315, W2 = 315, W3 = 70
TL203	0.081 $\lambda$ , 11.08 $\Omega$	W = 8, L = 14.2	W = 315, L = 559
TL204, TL243	0.008 $\lambda$ , 47.12 $\Omega$	W1 = 1.27, W2 = 1.27, W3 = 1.52	W1 = 50, W2 = 50, W3 = 60
TL205, TL214	0.011 $\lambda$ , 47.12 $\Omega$	W1 = 1.27, W2 = 1.27, W3 = 2.03	W1 = 50, W2 = 50, W3 = 80
TL206, TL213, TL217, TL219	0.009 $\lambda$ , 9.74 $\Omega$	W1 = 9.25, W2 = 9.25, W3 = 1.52	W1 = 364, W2 = 364, W3 = 60
TL207	0.007 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 1.4	W = 50, L = 55
TL209	0.030 $\lambda$ , 9.74 $\Omega$	W = 9.25, L = 5.21	W = 364, L = 205
TL210	0.075 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 14.05	W = 50, L = 553
TL211, TL232	0.002 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 0.38	W = 50, L = 15
TL212	0.060 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 11.2	W = 50, L = 441
TL215	0.055 $\lambda$ , 9.74 $\Omega$	W = 9.25, L = 9.65	W = 364, L = 380
TL216	0.007 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 1.4	W = 50, L = 55
TL218	0.007 $\lambda$ , 47.12 $\Omega$	W1 = 1.27, W2 = 1.27, W3 = 1.27	W1 = 50, W2 = 50, W3 = 50
TL221	0.006 $\lambda$ , 38.69 $\Omega$	W = 1.7, L = 1.14	W = 67, L = 45
TL222, TL223	0.061 $\lambda$ , 38.69 $\Omega$	W = 1.7, L = 11.3	W = 67, L = 445
TL224	0.030 $\lambda$ , 51.46 $\Omega$	W = 1.1, L = 5.69	W = 43, L = 224
TL225	0.012 $\lambda$ , 38.69 $\Omega$	W = 1.7, L = 2.22	W = 67, L = 87
TL226	0.073 $\lambda$ , 11.08 $\Omega$	W = 8, L = 12.7	W = 315, L = 500
TL231	0.060 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 11.2	W = 50, L = 441
TL233	0.075 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 14.05	W = 50, L = 553
TL234	0.030 $\lambda$ , 9.74 $\Omega$	W = 9.25, L = 5.21	W = 364, L = 205
TL235, TL236	0.014 $\lambda$ , 9.74 $\Omega$	W1 = 9.25, W2 = 9.25, W3 = 2.36	W1 = 364, W2 = 364, W3 = 93
TL237, TL239	0.082 $\lambda$ , 47.12 $\Omega$	W = 1.27, L = 15.35	W = 50, L = 604
TL240, TL241	0.009 $\lambda$ , 47.12 $\Omega$	W1 = 1.27, W2 = 1.27, W3 = 1.78	W1 = 50, W2 = 50, W3 = 70
TL242	0.007 $\lambda$ , 47.12 $\Omega$	W1 = 1.27, W2 = 1.27, W3 = 1.27	W1 = 50, W2 = 50, W3 = 50
TL245	0.017 $\lambda$ , 11.08 $\Omega$	W = 8, L = 2.92	W = 315, L = 115

Reference Circuit (cont.)



Reference circuit assembly diagram (not to scale)

Component ID	Description	Manufacturer	P/N
<b>Input</b>			
C101	Chip capacitor, 33 pF	ATC	100B330FW500XB
C102	Chip capacitor, 10000 pF	ATC	200B103MW
C103	Chip capacitor, 4.7 pF	ATC	100B4R7BW500XB
C104	Chip capacitor, 4.7 $\mu$ F	Nichicon	F931C475MAA
C105	Chip capacitor, 10000 pF	ATC	200B103MW
C106, C107	Chip capacitor, 4.8 pF	ATC	100B4R8BW500XB
C108	Chip capacitor, 1.5 pF	ATC	100B1R5BW500XB
C109	Chip capacitor, 8.2 pF	ATC	100B8R2BW500XB
C801, C804	Chip capacitor, 0.1 $\mu$ F	Panasonic Electronic Components	ECJ-3VB1H104K
C802, C803, C805	Chip capacitor, 1,000 pF	Panasonic Electronic Components	ECJ-1VB1H102K
R801	Resistor, 1.0k $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ102V
R802	Resistor, 1.3k $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ132V
R803	Resistor, 1.2k $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ122V
R804, R805	Resistor, 10 $\Omega$	Panasonic Electronic Components	ERJ-8GEYJ100V

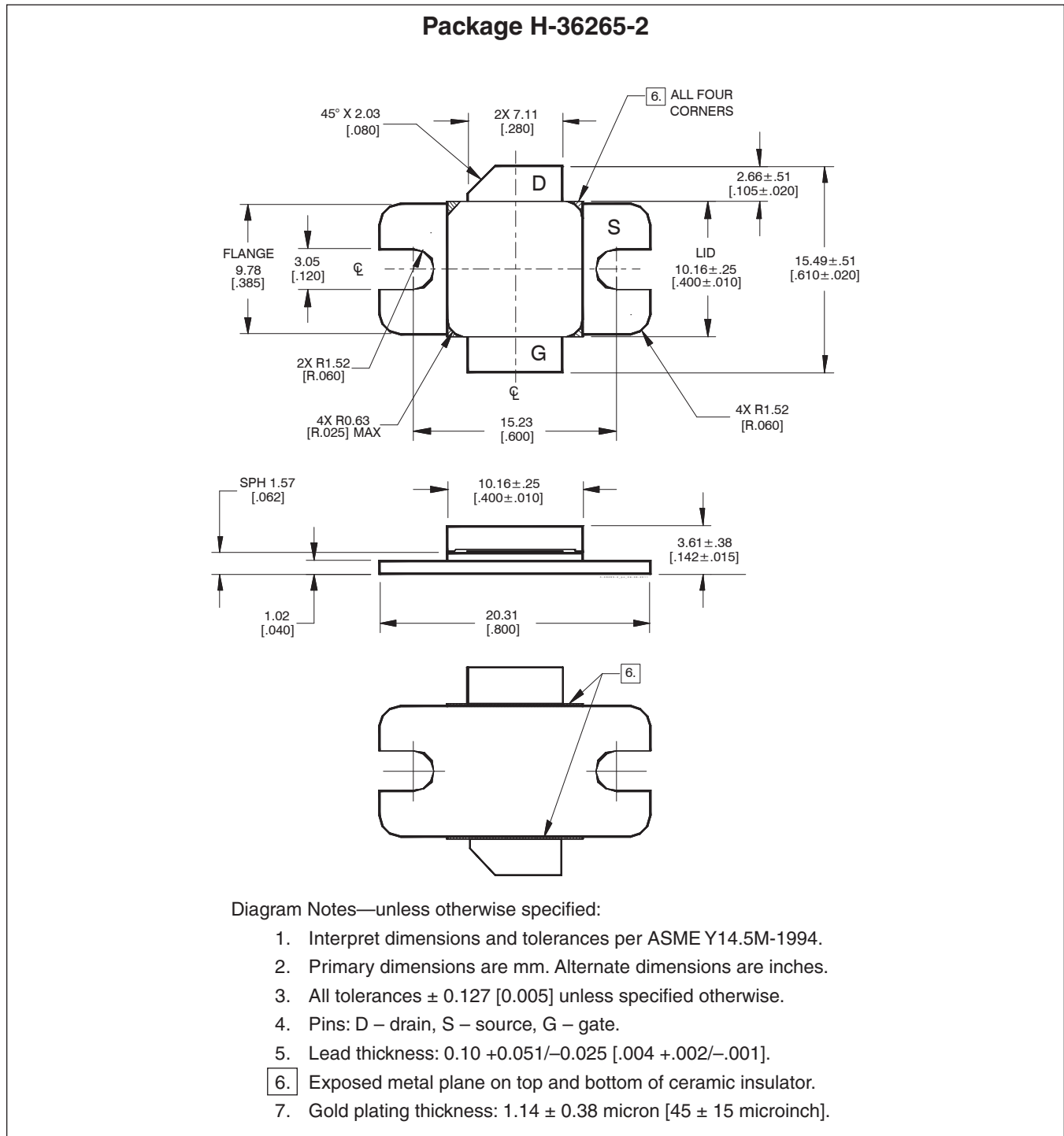
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**Reference Circuit** (cont.)

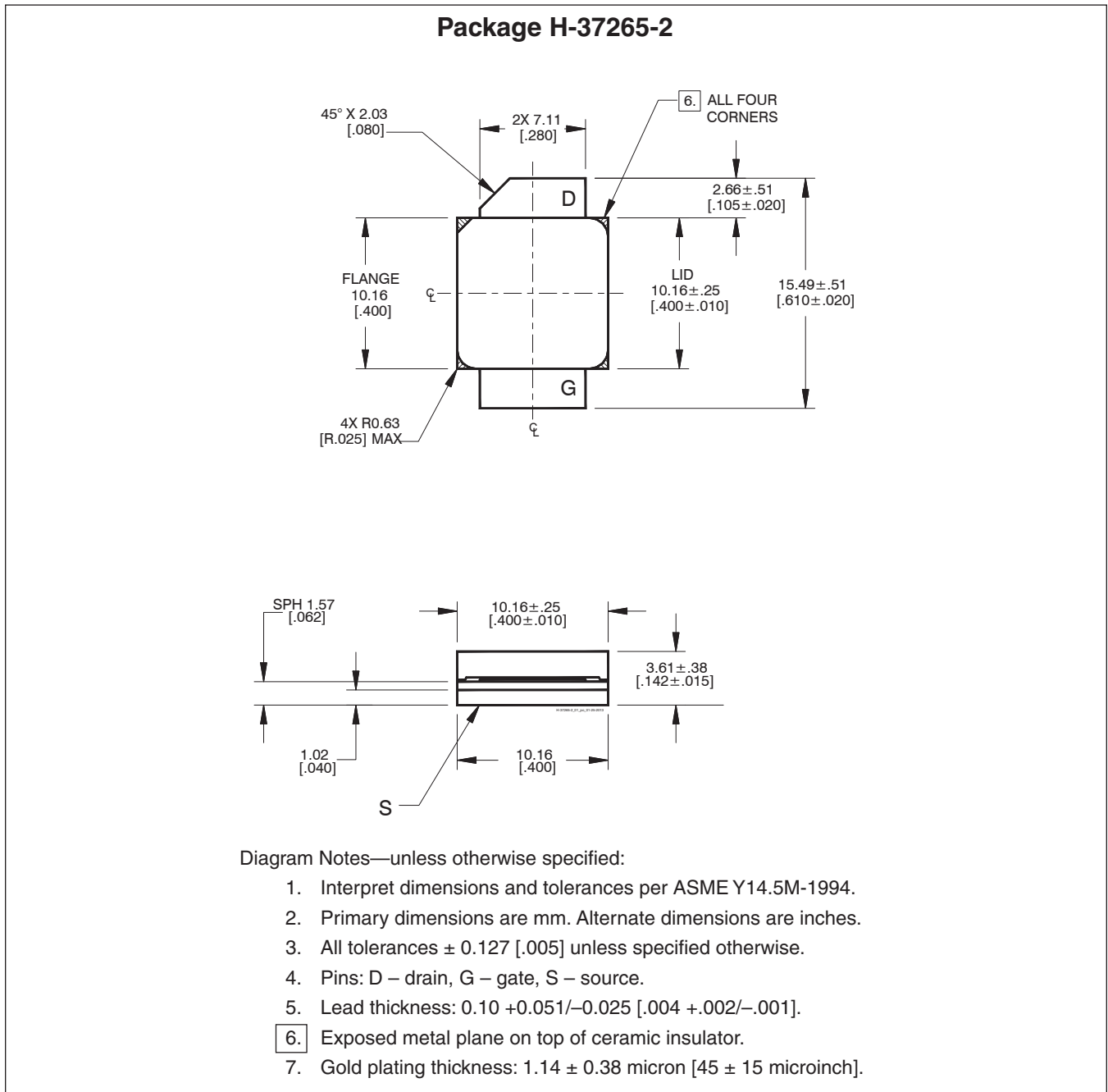
Component ID	Description	Manufacturer	P/N
<b>Input</b> (cont.)			
S1	Transistor	Fairchild Semiconductor	BCP56
S2	Potentiometer, 2k $\Omega$	Bourns Inc.	3224W-1-202E
S3	Voltage Regulator	National Semiconductor	LM7805
<b>Output</b>			
C201	Chip capacitor, 1 pF	ATC	100B0R9BW500XB
C202, C207, C215, C216	Chip capacitor, 1.0 $\mu$ F	ATC	281M5002106K
C203, C213	Chip capacitor, 0.1 $\mu$ F	Panasonic Electronic Components	ECJ-3VB1H104K
C204, C212	Chip capacitor, 1 $\mu$ F	AVX Corporation	2225PC105KAT1A
C205, C209	Capacitor, 10 $\mu$ F	Taiyo Yuden	UMK325C7106MM-T
C206, C208	Chip capacitor, 33 pF	ATC	100B330JW500XB
C210, C211	Chip capacitor, 3 pF	ATC	100B2R5BW500XB
C214	Chip capacitor, 33 pF	ATC	100B330FW500XB

See next page for package outline

## Package Outline Specifications



Package Outline Specifications (cont.)



Find the latest and most complete information about products and packaging at the Infineon Internet page <http://www.infineon.com/rfpower>

## Revision History

Revision	Date	Data Sheet	Page	Subjects (major changes in comparison with previous revision)
01	2010-09-02	Advance	All	New product PTFB090801FA, proposed only.
02	2010-11-05	Advance	All	Product number revised.
03	2011-09-08	Advance	All	Added eared package H-36265-2
04	2012-02-23	Production	All	Products released to production: specifications finalized, circuit information added.
05	2013-01-23	Production	All	Version 2 (V2) products will replace previous Version 1 (V1) products. No change to form, fit or function.
05.1	2014-07-08	Production	7 10-11	Correct label for output schematic. Identify component manufacturer and part number.
05.2	2016-06-09	Production	2	Updated ordering code to R0

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